Linear Tactile Nanodevice with Resolution on Par with Human Finger

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Abstract
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Keywords: Electron Tunneling, Nanoparticle self-assembly, Robotics, Tactile sensor, Thin film device
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Abstract

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1. INTRODUCTION

Recently, Bill Gates speculated that after the Personal Computer, a humanoid robot in every home would be the next revolution that would affect our lives intrinsically (1). Excluding taste, among the four basic senses, touch at resolution on par with human finger remains a challenge. Without a high resolution and sensitivity large area tactile device, also sometimes referred to as electronic skin, the humanoid robot may find it difficult to pour and deliver a glass of water to its master (2), or fold the laundry. The current tactile devices with active area of over 1 cm$^2$ have a resolution of ~1-2 mm (3) in contrast to human finger that has a resolution of ~40 μm (4) allowing us to feel a filament of hair on a smooth surface that has a typical diameter of ~100 μm. Recently, by self-assembling layers of nanoparticles by simple solution deposition process invented by Decher (5) we fabricated a large area device of thickness ~100 nm to convert compressive stress distribution or pressure on physical contact to light (6). By imaging the distribution of emitted light on a digital camera a “stress image” can be obtained that resolves the distribution of contact-pressure at a resolution of ~20 μm (6). Apart from the resolution on par with human sensitivity at contact pressures of 10-60 KPa that are comparable to the human touch, the approach has two practical advantages: (a) The fabrication process that is essentially sequential dip-coating followed by washing and drying will allow deposition of thin film device on large surface of area comparable to displays. (b) The response of the device, i.e., the intensity of light, is linearly proportional to applied stress. The linear relationship makes the grey-scale of the stress-image quantitatively comparable to the contact-pressure distribution. In this report, we present our observations that indicate why an electron tunneling based device that is intrinsically non-linear leads to highly linear response.

2. DEVICE CHARACTERISTICS

The ~100 nm thick nanodevice is a film (Fig. 1) consisting of alternating layers of Au (10 nm diameter) and CdS (3 nm diameter) nanoparticles separated by dielectric layers (DL), composed of stacked alternating layers of poly(styrene sulfonate) (PSS) and poly(allylamine hydrochloride) (PAH) (6). The 2.5 by 2.5 cm device is made by layer-by-layer self-assembly process (5) on a sputter deposited ~400 nm thick transparent conductive electrode coating of indium-tin-oxide (ITO) on glass. Finally, a flexible electrode (Au on polymer film) is placed on the top of the multilayered to make a contact. The particular device described here has three Au layers and two CdS layers, with 4 layers each of PAH and PSS as the inter-lying DL.

The film is insulating in the in-plane direction (6). In the vertical direction, the film is conducting due to tunneling between the Au and CdS layers. The current density, J, through the film as a function of bias, V, between the ITO and Au electrode, under a uniform pressure (i.e., compressive stress) σ, is shown in Fig. 2(a). The uniform pressure is applied by placing an optically flat quartz disk on the flexible Au electrode. The nonlinear J-V curve is fit based on a model combining the field assisted electron tunneling current (7) through the nanoparticles and the ionic (leakage) current due to ions in the polyelectrolyte. The total current (solid curve in Fig. 2(a)) is therefore modeled as,

$$J = J_r + J_f = P \exp \left( -\frac{aK}{V} \right) + \frac{V}{R}$$

(1)
In the first term due to tunneling, “a” is the (vertical) inter-particle distance, “K” is a critical field for activated tunneling that depends on the work functions of the particles, and “P” at constant temperature is proportional to V/m and the number density of carriers for conduction.(7). The second term due to the mobile ions (H\(^+\), Na\(^-\) and OH\(^-\), Cl\(^-\)) in the polyelectrolytes, “R”, is the ohmic resistance that is proportional to the distance between the electrodes. The fits are performed as a two step process: (i) At low V, the current is dominated by ionic current. Thus, the slope of the linear region at low-V is 1/R. The estimated resistivity of \(\sim 1.6 \times 10^8 \Omega \cdot m\) is reasonable for ion conductivity in PSS and PAH under ambient humidity. (ii) Thus, J-(V/R) is J\(_t\) that is fit by a single exponential to obtain (Ka) and P. Consistent with the theory on field-assisted tunneling, P~V\(^2\) (Fig.2(b)). Assuming ‘a’ (at \(\sigma = 0\)) \sim 5 nm, the critical field K of \(\sim 10^9\) V/m is reasonable. Because, electroluminescence will occur only when tunneling through CdS occurs, electroluminescence intensity, I\(_{EL}\), should be measurable above the bias of \(\sim 8\pm 1V\) when the total J begins to increase beyond the straight line (i.e., J\(_t\)) (Fig.2(a)). (Fig. 2(c)) is consistent with electroluminescence initiation at \(\sim 8\pm 1V\).

As the electroluminescence intensity from the device is virtually continuous (because inter-particle spacing is well below 25 nm), the resolution of the stress image is determined by the optics and the CCD camera and the “smearing” of the stress due to finite thickness of the plastic backing for the Au-electrode. Using the current device the stress distribution image due to the embossing of “Ashok Chinha” on 5 Rupee coin of India is clearly visible by pressing the coin at a reasonable load (Fig. 2(d))(6). For the CCD with a 512x512 array of \(\sim 16\) \(\mu\)m pixels, the I\(_{EL}\) is well over noise level to achieve lateral spatial resolution of at least \(\sim 20\) \(\mu\)m and the height modulation of \(\sim 10\) \(\mu\)m is measurable, indicating the device is fairly deformable (6). The linearity of the device is shown in Fig. 3(a). Both J and I\(_{EL}\) increases linearly with increasing magnitude of the compressive stress. The linearity of the device is due to the dominance of ‘P’ for modulation of tunneling current (Fig. 3(b)). Although, the tunneling process has an exponential dependence on ‘a’ that decreases with increasing \(\sigma\) (eq. (1)), the linear change in ‘P’ with load (\(\sim \sigma\)) dominates the modulation of tunneling process (i.e., current). Physically, ‘P’ is proportional to electron density of conduction electrons. At fixed temperature, the electron conduction density is constant. Thus, the increase in ‘P’ is proportional to the increase in number of percolation channels between the electrodes - as load increases, the number density of percolating channels of nanoparticles traversing through the thickness increases linearly causing a linear increase in ‘P’.

3. SUMMARY AND CONCLUSION

We have briefly discussed the characteristics of a thin film tactile device based on electron tunneling phenomena that converts applied stress to electroluminescent light. By focusing the electroluminescent light on a camera a high resolution stress-image is obtained. The tunneling current is modulated by altering the percolation behavior of the nanoparticle clusters leading to linear response.

4. REFERENCES